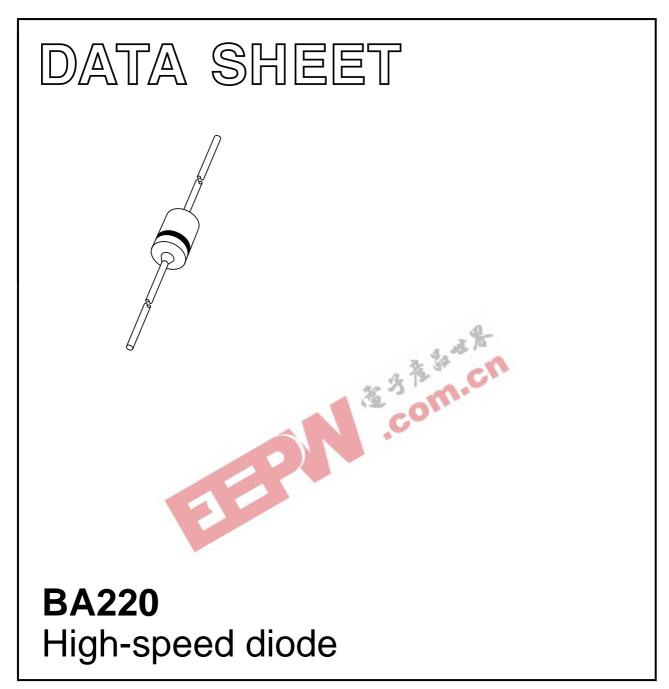
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of April 1996 File under Discrete Semiconductors, SC01





High-speed diode

BA220

FEATURES

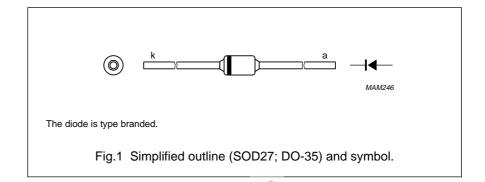
- · Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- · General application
- Continuous reverse voltage: max. 10 V
- · Repetitive peak reverse voltage: max. 10 V
- Repetitive peak forward current: max. 400 mA.

APPLICATIONS

· High-speed switching.

DESCRIPTION

The BA220 is a high-speed switching diode fabricated in planar technology, and encapsulated in the hermetically sealed leaded glass SOD27 (DO-35) package.



LIMITING VALUES n accordance with the Absolute Maximum Rating System (IEC 134).					
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage	Co.	_	10	V
V _R	continuous reverse voltage		_	10	V
I _F	continuous forward current	see Fig.2; note 1	_	200	mA
I _{FRM}	repetitive peak forward current		_	400	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	9	Α
		t = 100 μs	_	3	Α
		t = 1 s	_	1	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	350	mW
T _{stg}	storage temperature		-65	+200	°C
Tj	junction temperature		_	200	°C

Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

Philips Semiconductors Product specification

High-speed diode

BA220

ELECTRICAL CHARACTERISTICS

 T_j = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	see Fig.3			
		$I_F = 0.1 \text{ mA}$	460	520	mV
		I _F = 1 mA	560	620	mV
		I _F = 5 mA	640	700	mV
		I _F = 10 mA	680	750	mV
		I _F = 100 mA	825	950	mV
I _R	reverse current	see Fig.5			
		V _R = 10 V	_	1.5	μΑ
		V _R = 10 V; T _j = 150 °C	_	50	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	_	2.5	pF
t _{rr}	reverse recovery time	when switched from I _F = 10 mA to	_	4	ns
		I_R = 60 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.7			
V _{fr}	forward recovery voltage	when switched from I _F = 400 mA;	_	2.0	V
		$t_r = 30 \text{ ns}$; see Fig.8			

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
R _{th j-a}	thermal resistance from junction to ambient	lead length 10 mm; note 1	500	K/W

Note

1. Device mounted on a printed circuit-board without metallization pad.

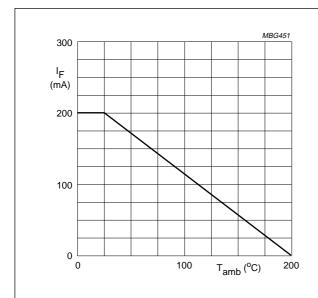
1996 Sep 03 3

Philips Semiconductors Product specification

High-speed diode

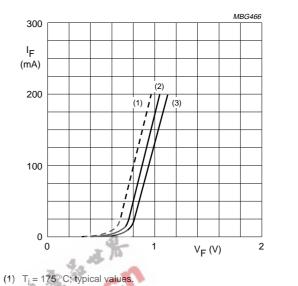
BA220

GRAPHICAL DATA



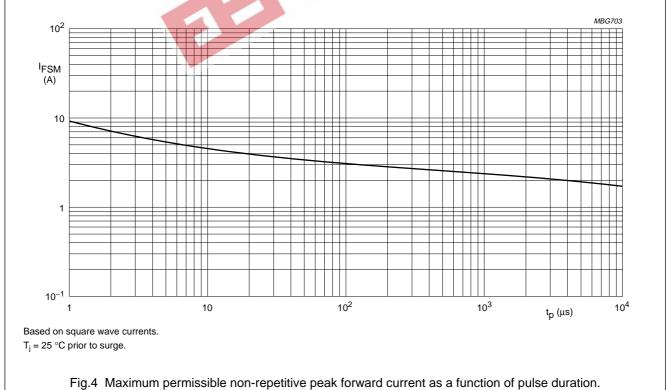
Device mounted on an FR4 printed-circuit board; lead length 10 mm.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (2) T_j = 25 °C; typical values.
 (3) T_j = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



4

Philips Semiconductors Product specification

High-speed diode

BA220

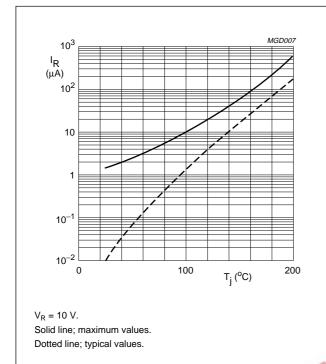


Fig.5 Reverse current as a function of junction temperature.

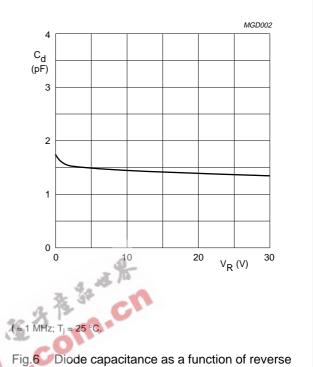


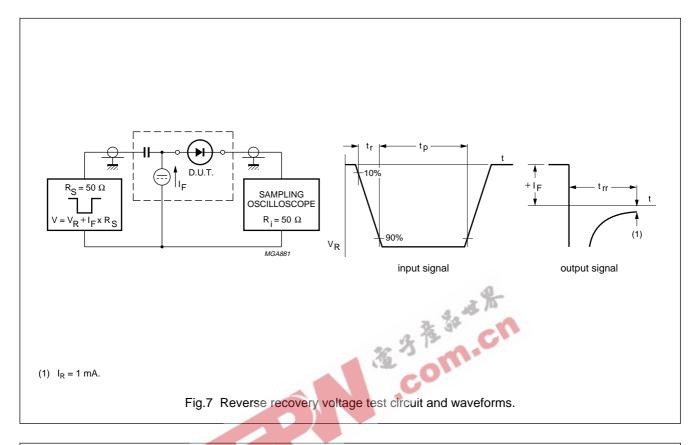
Fig.6 Diode capacitance as a function of reverse voltage; typical values.

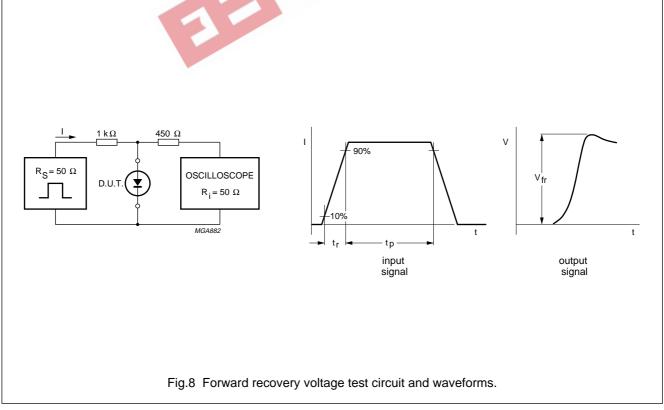
1996 Sep 03 5

Philips Semiconductors Product specification

High-speed diode

BA220





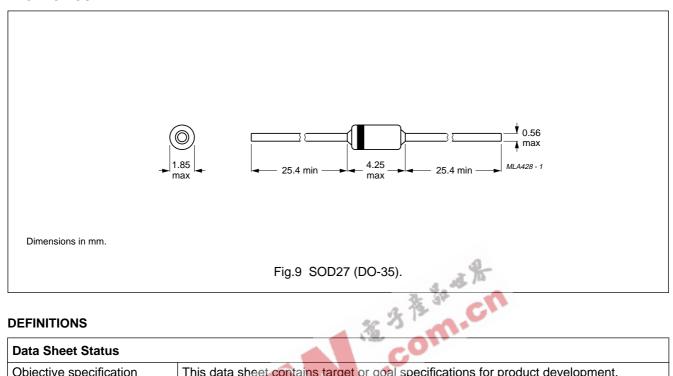
6

Philips Semiconductors Product specification

High-speed diode

BA220

PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information			

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Where application information is given, it is advisory and does not form part of the specification.